Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	I.
Glass	
Overall Length:	
	hes and 0.350 inches
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.215 inc	hes and 0.265 inches
Electrode Internal	Ily-electrically Connected To Case:
Cathode	
Mounting Method	:
Terminal	
Features Provide	d:
Hermetically sealed	d case
Semiconductor M	aterial:
Silicon	
Voltage Rating In	Volts Per Characteristic:
22.8 regulator vol	tage
Current Rating Pe	er Characteristic:
40.00 milliamperes	source cutoff current horsepower metric
Power Rating Per	Characteristic:
1.0 watts small-sig	nal input power, common-collector preset
Maximum Operati	ing Tempurature Per Measurement Point:
175.0 degrees cels	sius ambient air
Test Data Docum	ent:
81349-mil-s-19500	specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes o	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type An	d Quantity:
2 uninsulated wire	lead
Specification Data	a:
81349-mil-s-19500	/115 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	